Gokin

GEM G12R/108D



High Efficiency

Module efficiency up to 23.2% based on N-Type wafer and TOPCon technology

Excellent Energy Yield

More power output in field operation due to better thermal behaviors, weak-light performance and bifaciality

Anti-degradation

Unsusceptible to LID, LeTID and less annual degradation due to special charateristics of N-Type

Quality Guarantee

High module quality ensures long-term reliability

-Year
Product Warranty

-Year

IEC 61215(2021) / IEC 61730(2023)
ISO 9001: 2015 / ISO Quality Management System
Anti-PID / Ammonia / Salt-mist / Dust-proof
Made in China